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Docket No. 740756-2228
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2/13/02

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of)
Hongyong ZHANG et al.) Group Art Unit: 2823
Application Serial No. 09/726,337) Examiner: W. Coleman
Filed: December 1, 2000)
For: METHOD FOR PRODUCING A)
SEMICONDUCTOR DEVICE INCLUDING)
DOPING WITH A CATALYST THAT IS A)
GROUP IV ELEMENT (TO BE AMENDED))

AMENDMENT

Honorable Commissioner of Patents
Washington, D.C. 20231

RECEIVED
FEB - 8 2002
TC 2800 MAIL ROOM

Sir:

Responsive to the Office Action dated **October 3, 2001**, the shortened statutory period for response having been extended 1 month until **February 3, 2002**, please consider the following amendments and remarks in connection with the above-identified application.

IN THE TITLE OF THE INVENTION:

Please delete the title of the invention in its entirety and substitute therefor the following title of the invention: "A SEMICONDUCTOR DEVICE HAVING CHANNEL FORMATION REGION COMPRISING SILICON AND CONTAINING A GROUP IV ELEMENT."